

# NLHV4051, NLHV4052, NLHV4053



ON Semiconductor®

[www.onsemi.com](http://www.onsemi.com)

## Analog Multiplexers/Demultiplexers

The NLHV4051, NLHV4052, and NLHV4053 analog multiplexers are digitally-controlled analog switches. The NLHV4051 effectively implements an SP8T solid state switch, the NLHV4052 a DP4T, and the NLHV4053 a Triple SPDT. All three devices feature low ON impedance and very low OFF leakage current. Control of analog signals up to the complete supply voltage range can be achieved.

### Features

- Triple Diode Protection on Control Inputs
- Switch Function is Break Before Make
- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- Analog Voltage Range ( $V_{DD} - V_{EE}$ ) = 3.0 to 18 V  
Note:  $V_{EE}$  must be  $\leq V_{SS}$
- Linearized Transfer Characteristics
- Low-noise – 12 nV/ $\sqrt{\text{Cycle}}$ ,  $f \geq 1.0$  kHz Typical
- Pin-for-Pin Replacement for CD4051, CD4052, and CD4053
- For 4PDT Switch, See MC14551B
- For Lower  $R_{ON}$ , Use the HC4051, HC4052, or HC4053 High-Speed CMOS Devices
- These Devices are Pb-Free and are RoHS Compliant

### MAXIMUM RATINGS (Voltages Referenced to $V_{SS}$ )

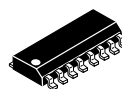
Symbol	Parameter	Value	Unit
$V_{DD}$	DC Supply Voltage Range (Referenced to $V_{EE}$ , $V_{SS} \geq V_{EE}$ )	-0.5 to +18.0	V
$V_{in}$ , $V_{out}$	Input or Output Voltage Range (DC or Transient) (Referenced to $V_{SS}$ for Control Inputs and $V_{EE}$ for Switch I/O)	-0.5 to $V_{DD} + 0.5$	V
$I_{in}$	Input Current (DC or Transient) per Control Pin	+10	mA
$I_{SW}$	Switch Through Current	$\pm 25$	mA
$P_D$	Power Dissipation per Package (Note 1)	500	mW
$T_A$	Ambient Temperature Range	-55 to +125	°C
$T_{stg}$	Storage Temperature Range	-65 to +150	°C
$T_L$	Lead Temperature (8-Second Soldering)	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

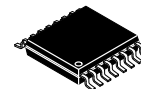
1. Temperature Derating: "D/DW" Packages: -7.0 mW/°C From 65°C To 125°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation,  $V_{in}$  and  $V_{out}$  should be constrained to the range  $V_{SS} \leq (V_{in} \text{ or } V_{out}) \leq V_{DD}$ .

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either  $V_{SS}$ ,  $V_{EE}$  or  $V_{DD}$ ). Unused outputs must be left open.



SOIC-16  
D SUFFIX  
CASE 751B

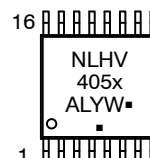


TSSOP-16  
DT SUFFIX  
CASE 948F

### MARKING DIAGRAMS



SOIC-16



TSSOP-16

- x = 1, 2, or 3
- A = Assembly Location
- WL, L = Wafer Lot
- Y = Year
- WW, W = Work Week
- G or ■ = Pb-Free Package

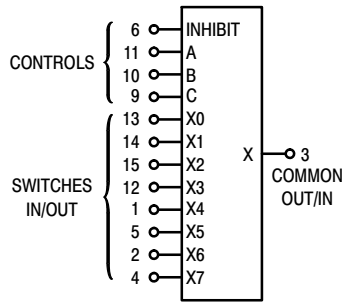
(Note: Microdot may be in either location)

### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 9 of this data sheet.

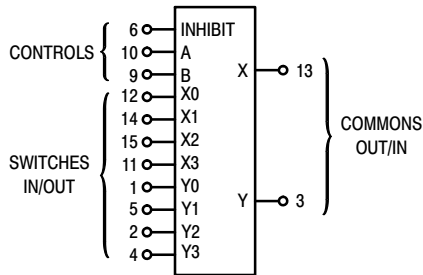
# NLHV4051, NLHV4052, NLHV4053

## NLHV4051 8-Channel Analog Multiplexer/Demultiplexer



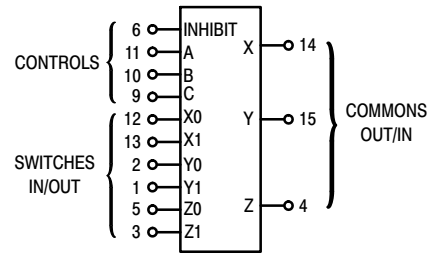
$V_{DD}$  = PIN 16  
 $V_{SS}$  = PIN 8  
 $V_{EE}$  = PIN 7

## NLHV4052 Dual 4-Channel Analog Multiplexer/Demultiplexer



$V_{DD}$  = PIN 16  
 $V_{SS}$  = PIN 8  
 $V_{EE}$  = PIN 7

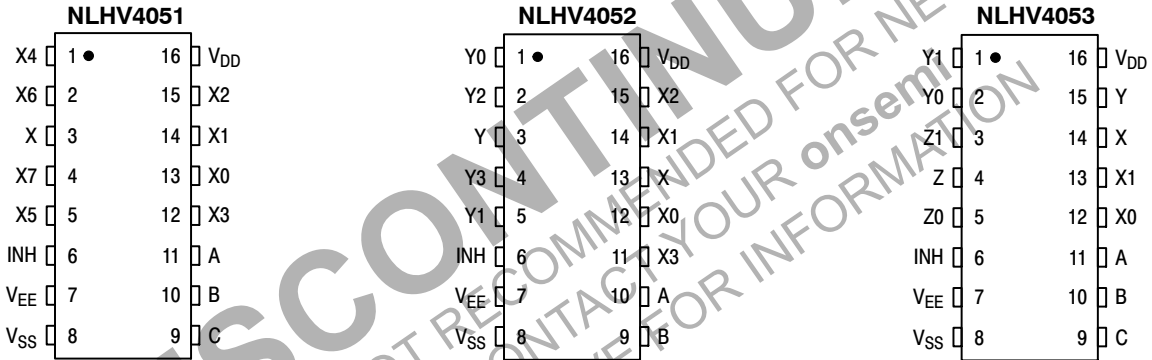
## NLHV4053 Triple 2-Channel Analog Multiplexer/Demultiplexer



$V_{DD}$  = PIN 16  
 $V_{SS}$  = PIN 8  
 $V_{EE}$  = PIN 7

Note: Control Inputs referenced to  $V_{SS}$ . Analog Inputs and Outputs reference to  $V_{EE}$ .  $V_{EE}$  must be  $\leq V_{SS}$ .

### PIN ASSIGNMENT



DISCONTINUED

THIS DEVICE IS NOT RECOMMENDED FOR NEW DESIGN

PLEASE CONTACT YOUR INFORMATION REPRESENTATIVE FOR INFORMATION

# NLHV4051, NLHV4052, NLHV4053

## ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	V <sub>DD</sub>	Test Conditions	-55°C		25°C			125°C		Unit
				Min	Max	Min	Typ (Note 2)	Max	Min	Max	

### SUPPLY REQUIREMENTS (Voltages Referenced to V<sub>EE</sub>)

Power Supply Voltage Range	V <sub>DD</sub>	-	V <sub>DD</sub> - 3.0 ≥ V <sub>SS</sub> ≥ V <sub>EE</sub>	3.0	18	3.0	-	18	3.0	18	V
Quiescent Current Per Package	I <sub>DD</sub>	5.0	Control Inputs: V <sub>in</sub> = V <sub>SS</sub> or V <sub>DD</sub> . Switch I/O: V <sub>EE</sub> ≤ V <sub>I/O</sub> ≤ V <sub>DD</sub> , and ΔV <sub>switch</sub> ≤ 500 mV (Note 3)	-	5.0	-	0.005	5.0	-	150	μA
		10		-	10	-	0.010	10	-	300	
		15		-	20	-	0.015	20	-	600	
Total Supply Current (Dynamic Plus Quiescent, Per Package)	I <sub>D(AV)</sub>	5.0 10 15	T <sub>A</sub> = 25°C only (The channel component, (V <sub>in</sub> - V <sub>out</sub> )/R <sub>on</sub> , is not included.)	Typical				(0.07 μA/kHz) f + I <sub>DD</sub> (0.20 μA/kHz) f + I <sub>DD</sub> (0.36 μA/kHz) f + I <sub>DD</sub>			μA

### CONTROL INPUTS — INHIBIT, A, B, C (Voltages Referenced to V<sub>SS</sub>)

Low-Level Input Voltage	V <sub>IL</sub>	5.0 10 15	R <sub>on</sub> = per spec, I <sub>off</sub> = per spec	-	1.5 3.0 4.0	-	2.25 4.50 6.75	1.5 3.0 4.0	-	1.5 3.0 4.0	V
High-Level Input Voltage	V <sub>IH</sub>	5.0 10 15	R <sub>on</sub> = per spec, I <sub>off</sub> = per spec	3.5 7.0 11	-	3.5 7.0 11	2.75 5.50 8.25	-	3.5 7.0 11	-	V
Input Leakage Current	I <sub>in</sub>	15	V <sub>in</sub> = 0 or V <sub>DD</sub>	-	±0.1	-	±0.00001	±0.1	-	1.0	μA
Input Capacitance	C <sub>in</sub>	-		-	-	-	5.0	7.5	-	-	pF

### SWITCHES IN/OUT AND COMMONS OUT/IN — X, Y, Z (Voltages Referenced to V<sub>EE</sub>)

Recommended Peak-to-Peak Voltage Into or Out of the Switch	V <sub>I/O</sub>	-	Channel On or Off	0	V <sub>DD</sub>	0	-	V <sub>DD</sub>	0	V <sub>DD</sub>	V <sub>PP</sub>
Recommended Static or Dynamic Voltage Across the Switch (Note 3) (Figure 5)	ΔV <sub>switch</sub>	-	Channel On	0	600	0	-	600	0	300	mV
Output Offset Voltage	V <sub>OO</sub>	-	V <sub>in</sub> = 0 V, No Load	-	-	-	10	-	-	-	μV
ON Resistance	R <sub>on</sub>	5.0	ΔV <sub>switch</sub> ≤ 500 mV (Note 3) V <sub>in</sub> = V <sub>IL</sub> or V <sub>IH</sub> (Control), and V <sub>in</sub> = 0 to V <sub>DD</sub> (Switch)	-	800	-	250	1050	-	1200	Ω
		10		-	400	-	120	500	-	520	
		15		-	220	-	80	280	-	300	
ΔON Resistance Between Any Two Channels in the Same Package	ΔR <sub>on</sub>	5.0		-	70	-	25	70	-	135	Ω
		10		-	50	-	10	50	-	95	
		15		-	45	-	10	45	-	65	
Off-Channel Leakage Current (Figure 10)	I <sub>off</sub>	15	V <sub>in</sub> = V <sub>IL</sub> or V <sub>IH</sub> (Control) Channel to Channel or Any One Channel	-	±100	-	±0.05	±100	-	±1000	nA
Capacitance, Switch I/O	C <sub>I/O</sub>	-	Inhibit = V <sub>DD</sub>	-	-	-	10	-	-	-	pF
Capacitance, Common O/I	C <sub>O/I</sub>	-	Inhibit = V <sub>DD</sub> (NLHV4051) (NLHV4052) (NLHV4053)	-	-	-	60	-	-	-	pF
				-	-	-	32	-	-	-	
				-	-	-	17	-	-	-	
Capacitance, Feedthrough (Channel Off)	C <sub>I/O</sub>	-	Pins Not Adjacent	-	-	-	0.15	-	-	-	pF
				-	-	-	0.47	-	-	-	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Data labeled "Typ" is not to be used for design purposes, but is intended as an indication of the IC's potential performance.

3. For voltage drops across the switch (ΔV<sub>switch</sub>) > 600 mV (> 300 mV at high temperature), excessive V<sub>DD</sub> current may be drawn, i.e. the current out of the switch may contain both V<sub>DD</sub> and switch input components. The reliability of the device will be unaffected unless the Maximum Ratings are exceeded. (See first page of this data sheet.)

# NLHV4051, NLHV4052, NLHV4053

## ELECTRICAL CHARACTERISTICS (Note 4) ( $C_L = 50 \text{ pF}$ , $T_A = 25^\circ\text{C}$ ) ( $V_{EE} \leq V_{SS}$ unless otherwise indicated)

Characteristic	Symbol	$V_{DD} - V_{EE}$ Vdc	Typ (Note 5) All Types	Max	Unit
Propagation Delay Times (Figure 6) Switch Input to Switch Output ( $R_L = 1 \text{ k}\Omega$ ) NLHV4051 $t_{PLH}, t_{PHL} = (0.17 \text{ ns/pF}) C_L + 26.5 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.08 \text{ ns/pF}) C_L + 11 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.06 \text{ ns/pF}) C_L + 9.0 \text{ ns}$ NLHV4052 $t_{PLH}, t_{PHL} = (0.17 \text{ ns/pF}) C_L + 21.5 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.08 \text{ ns/pF}) C_L + 8.0 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.06 \text{ ns/pF}) C_L + 7.0 \text{ ns}$ NLHV4053 $t_{PLH}, t_{PHL} = (0.17 \text{ ns/pF}) C_L + 16.5 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.08 \text{ ns/pF}) C_L + 4.0 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.06 \text{ ns/pF}) C_L + 3.0 \text{ ns}$	$t_{PLH}, t_{PHL}$	5.0	35	90	ns
		10	15	40	
		15	12	30	
		5.0	30	75	ns
		10	12	30	
		15	10	25	
		5.0	25	65	ns
		10	8.0	20	
		15	6.0	15	
Inhibit to Output ( $R_L = 10 \text{ k}\Omega$ , $V_{EE} = V_{SS}$ ) Output "1" or "0" to High Impedance, or High Impedance to "1" or "0" Level NLHV4051  NLHV4052  NLHV4053	$t_{PHZ}, t_{PLZ},$ $t_{PZH}, t_{PZL}$	5.0	350	700	ns
		10	170	340	
		15	140	280	
		5.0	300	600	ns
		10	155	310	
		15	125	250	
		5.0	275	550	ns
		10	140	280	
		15	110	220	
Control Input to Output ( $R_L = 1 \text{ k}\Omega$ , $V_{EE} = V_{SS}$ ) NLHV4051  NLHV4052  NLHV4053	$t_{PLH}, t_{PHL}$	5.0	360	720	ns
		10	160	320	
		15	120	240	
		5.0	325	650	ns
		10	130	260	
		15	90	180	
		5.0	300	600	ns
		10	120	240	
		15	80	160	
Second Harmonic Distortion ( $R_L = 10 \text{ k}\Omega$ , $f = 1 \text{ kHz}$ , $V_{in} = 5 \text{ V}_{PP}$ )	-	10	0.07	-	%
Bandwidth (Figure 7) ( $R_L = 50 \Omega$ , $V_{in} = 1/2 (V_{DD} - V_{EE})$ p-p, $C_L = 50 \text{ pF}$ $20 \text{ Log} (V_{out}/V_{in}) = -3 \text{ dB}$ )	BW	10	17	-	MHz
Off Channel Feedthrough Attenuation (Figure 7) $R_L = 1 \text{ k}\Omega$ , $V_{in} = 1/2 (V_{DD} - V_{EE})$ p-p $f_{in} = 4.5 \text{ MHz}$ — NLHV4051 $f_{in} = 30 \text{ MHz}$ — NLHV4052 $f_{in} = 55 \text{ MHz}$ — NLHV4053	-	10	-50	-	dB
Channel Separation (Figure 8) ( $R_L = 1 \text{ k}\Omega$ , $V_{in} = 1/2 (V_{DD} - V_{EE})$ p-p, $f_{in} = 3.0 \text{ MHz}$ )	-	10	-50	-	dB
Crosstalk, Control Input to Common O/I (Figure 9) ( $R_1 = 1 \text{ k}\Omega$ , $R_L = 10 \text{ k}\Omega$ Control $t_{TLH} = t_{THL} = 20 \text{ ns}$ , Inhibit = $V_{SS}$ )	-	10	75	-	mV

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

4. The formulas given are for the typical characteristics only at  $25^\circ\text{C}$ .

5. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

# NLHV4051, NLHV4052, NLHV4053

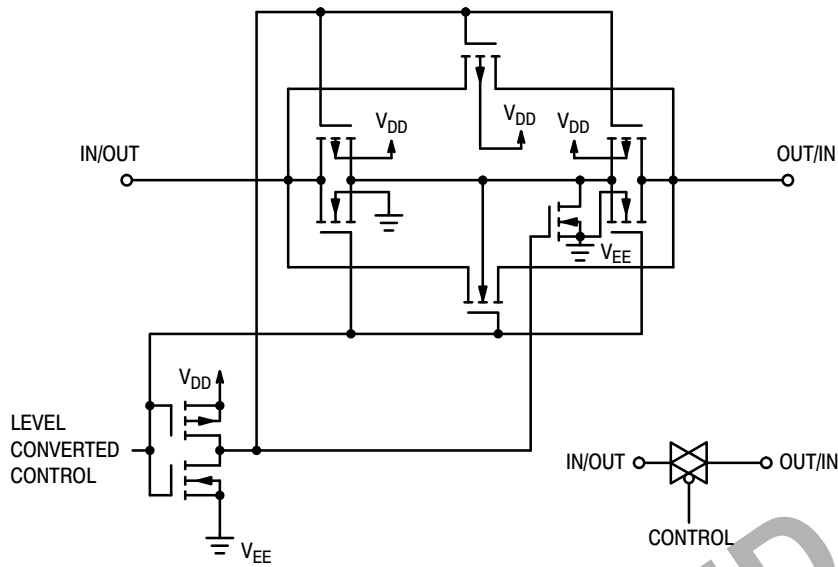


Figure 1. Switch Circuit Schematic

## TRUTH TABLE

Control Inputs			ON Switches		
Inhibit	Select		NLHV4051	NLHV4052	NLHV4053
	C*	B A			
0	0 0 0	X0	Y0 X0	Z0 Y0 X0	
0	0 0 1	X1	Y1 X1	Z0 Y0 X1	
0	0 1 0	X2	Y2 X2	Z0 Y1 X0	
0	0 1 1	X3	Y3 X3	Z0 Y1 X1	
0	1 0 0	X4		Z1 Y0 X0	
0	1 0 1	X5		Z1 Y0 X1	
0	1 1 0	X6		Z1 Y1 X0	
0	1 1 1	X7		Z1 Y1 X1	
1	x x x	None	None	None	

\*Not applicable for MC14052  
x = Don't Care

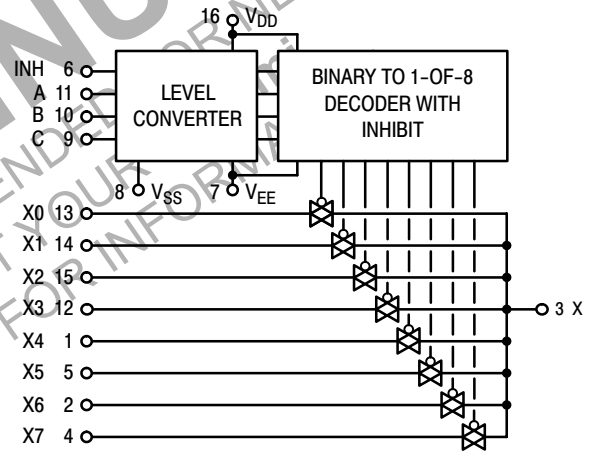


Figure 2. NLHV4051 Functional Diagram

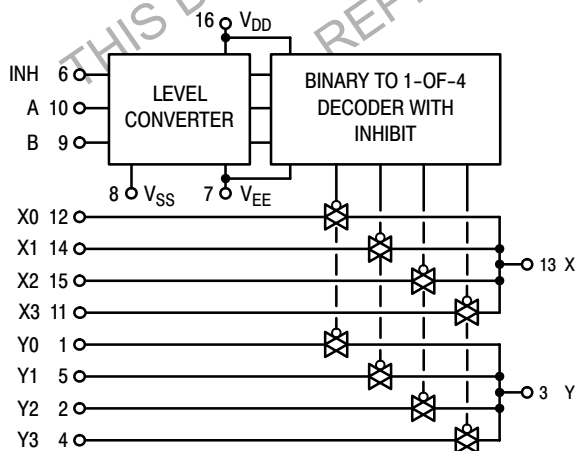


Figure 3. NLHV4052 Functional Diagram

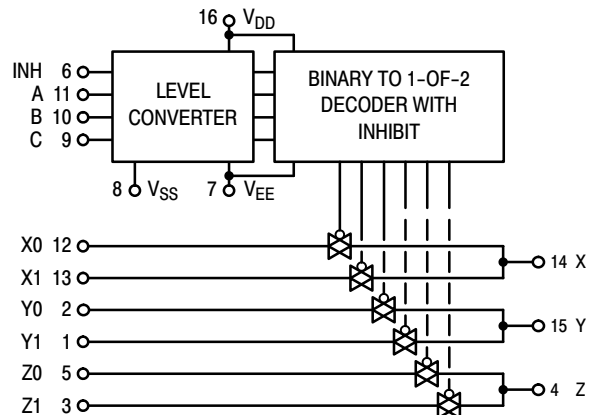


Figure 4. NLHV4053 Functional Diagram

TEST CIRCUITS

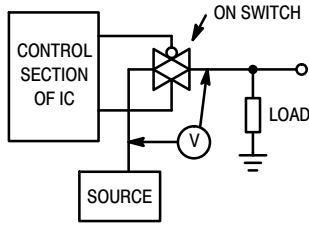


Figure 5.  $\Delta V$  Across Switch

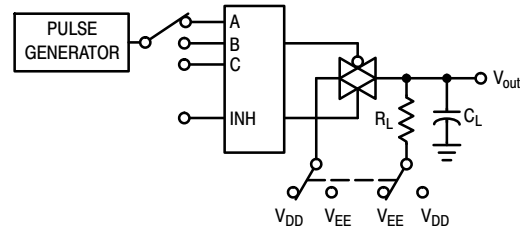


Figure 6. Propagation Delay Times, Control and Inhibit to Output

A, B, and C inputs used to turn ON or OFF the switch under test.

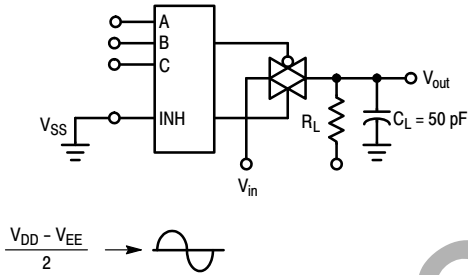


Figure 7. Bandwidth and Off-Channel Feedthrough Attenuation

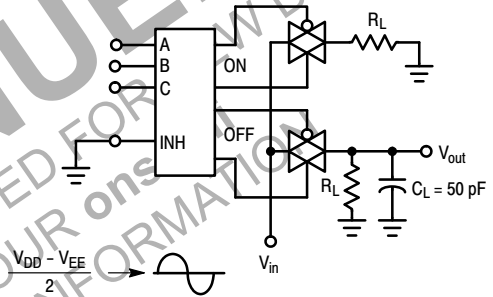


Figure 8. Channel Separation (Adjacent Channels Used For Setup)

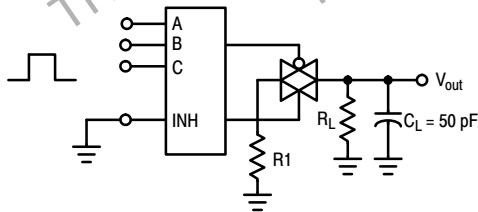


Figure 9. Crosstalk, Control Input to Common O/I

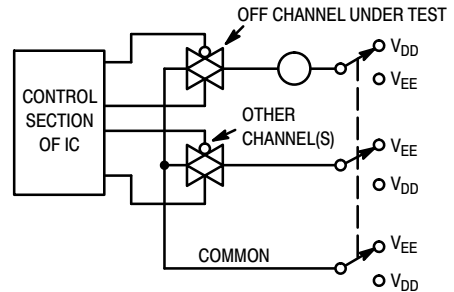
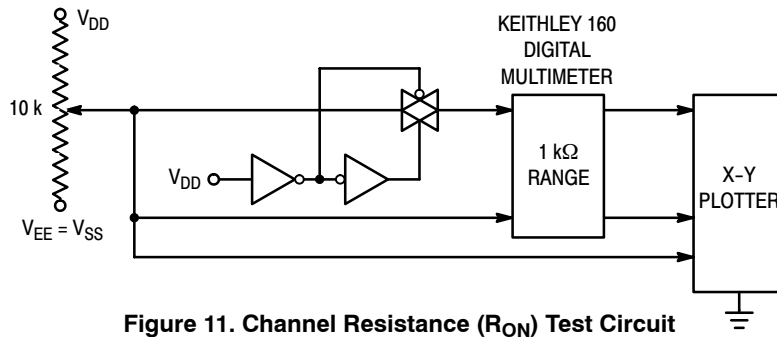


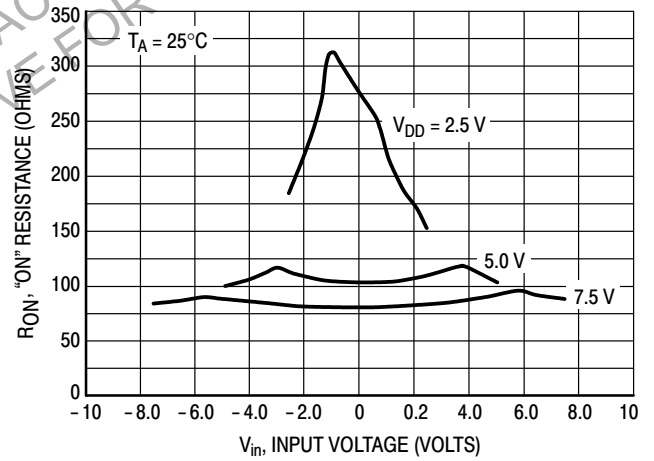
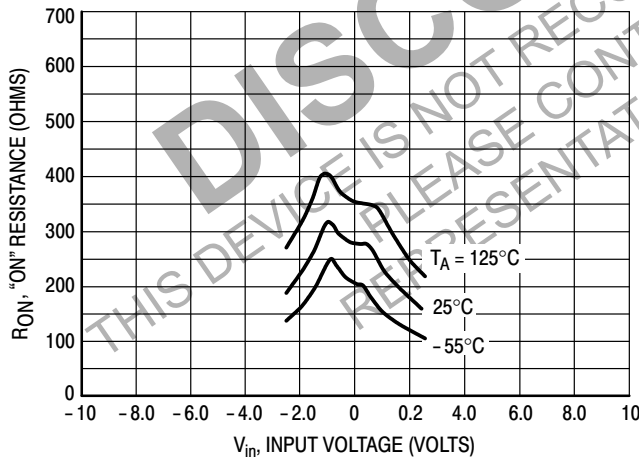
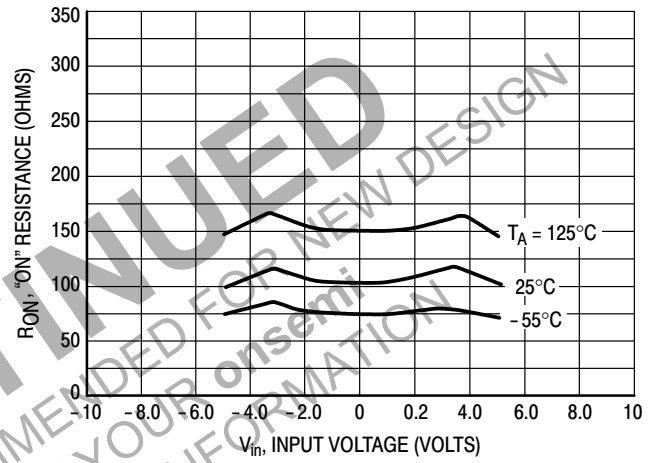
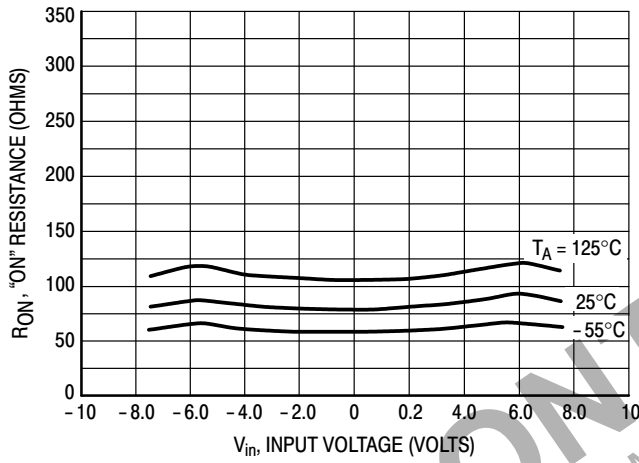
Figure 10. Off Channel Leakage

NOTE: See also Figures 7 and 8 in the MC14016B data sheet.

# NLHV4051, NLHV4052, NLHV4053



## TYPICAL RESISTANCE CHARACTERISTICS



# NLHV4051, NLHV4052, NLHV4053

## APPLICATIONS INFORMATION

Figure A illustrates use of the on-chip level converter detailed in Figures 2, 3, and 4. The 0-to-5 V Digital Control signal is used to directly control a 9 V<sub>p-p</sub> analog signal.

The digital control logic levels are determined by V<sub>DD</sub> and V<sub>SS</sub>. The V<sub>DD</sub> voltage is the logic high voltage; the V<sub>SS</sub> voltage is logic low. For the example, V<sub>DD</sub> = +5 V = logic high at the control inputs; V<sub>SS</sub> = GND = 0 V = logic low.

The maximum analog signal level is determined by V<sub>DD</sub> and V<sub>EE</sub>. The V<sub>DD</sub> voltage determines the maximum recommended peak above V<sub>SS</sub>. The V<sub>EE</sub> voltage determines the maximum swing below V<sub>SS</sub>. For the example, V<sub>DD</sub> - V<sub>SS</sub> = 5 V maximum swing above V<sub>SS</sub>; V<sub>SS</sub> - V<sub>EE</sub> = 5 V maximum swing below V<sub>SS</sub>. The example shows a ±4.5 V signal which allows a 1/2 volt margin at each

peak. If voltage transients above V<sub>DD</sub> and/or below V<sub>EE</sub> are anticipated on the analog channels, external diodes (D<sub>x</sub>) are recommended as shown in Figure B. These diodes should be small signal types able to absorb the maximum anticipated current surges during clipping.

The *absolute* maximum potential difference between V<sub>DD</sub> and V<sub>EE</sub> is 18.0 V. Most parameters are specified up to 15 V which is the *recommended* maximum difference between V<sub>DD</sub> and V<sub>EE</sub>.

Balanced supplies are not required. However, V<sub>SS</sub> must be greater than or equal to V<sub>EE</sub>. For example, V<sub>DD</sub> = +10 V, V<sub>SS</sub> = +5 V, and V<sub>EE</sub> = -3 V is acceptable. See the Table below.

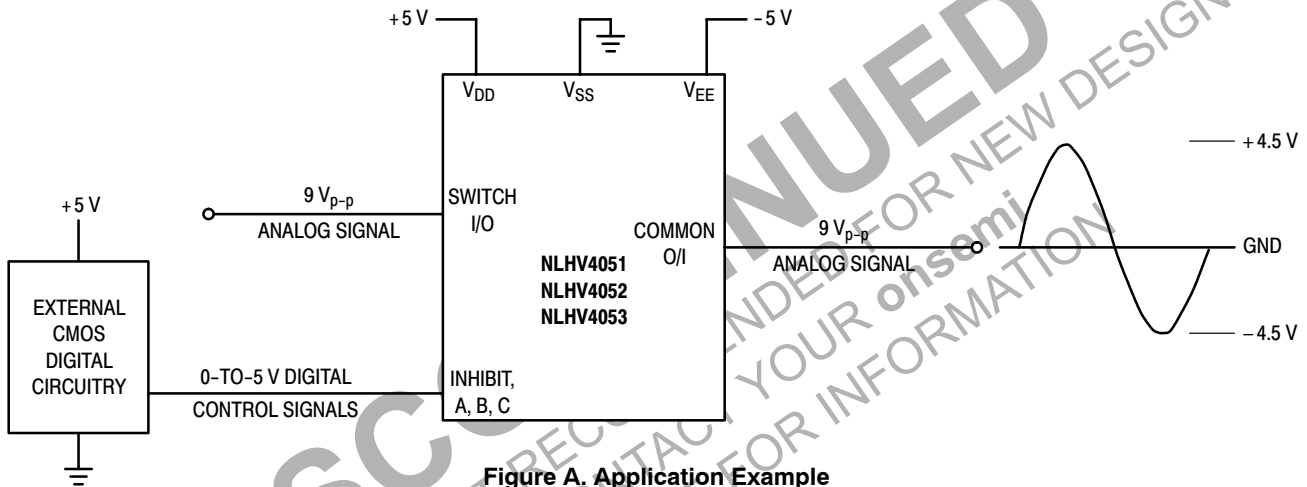


Figure A. Application Example

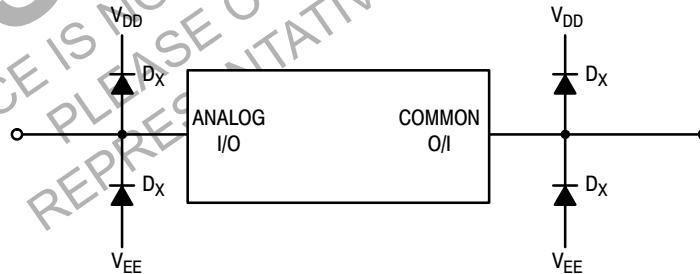


Figure B. External Germanium or Schottky Clipping Diodes

### POSSIBLE SUPPLY CONNECTIONS

V <sub>DD</sub> In Volts	V <sub>SS</sub> In Volts	V <sub>EE</sub> In Volts	Control Inputs Logic High/Logic Low In Volts	Maximum Analog Signal Range In Volts
+8	0	-8	+8/0	+8 to -8 = 16 V <sub>p-p</sub>
+5	0	-12	+5/0	+5 to -12 = 17 V <sub>p-p</sub>
+5	0	0	+5/0	+5 to 0 = 5 V <sub>p-p</sub>
+5	0	-5	+5/0	+5 to -5 = 10 V <sub>p-p</sub>
+10	+5	-5	+10/ +5	+10 to -5 = 15 V <sub>p-p</sub>



## NLHV4051, NLHV4052, NLHV4053

### ORDERING INFORMATION

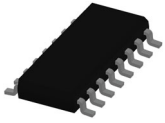
Device	Package	Shipping†
NLHV4051DR2G	SOIC-16 (Pb-Free)	2500 / Tape & Reel
NLHV4051DTR2G	TSSOP-16 (Pb-Free)	2500 / Tape & Reel
NLHV4052DR2G	SOIC-16 (Pb-Free)	2500 / Tape & Reel
NLHV4052DTR2G	TSSOP-16 (Pb-Free)	2500 / Tape & Reel
NLHV4053DR2G (In Development)	SOIC-16 (Pb-Free)	2500 / Tape & Reel
NLHV4053DTR2G (In Development)	TSSOP-16 (Pb-Free)	2500 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

**DISCONTINUED**  
THIS DEVICE IS NOT RECOMMENDED FOR NEW DESIGN  
PLEASE CONTACT YOUR onsemi  
REPRESENTATIVE FOR INFORMATION

# MECHANICAL CASE OUTLINE

## PACKAGE DIMENSIONS

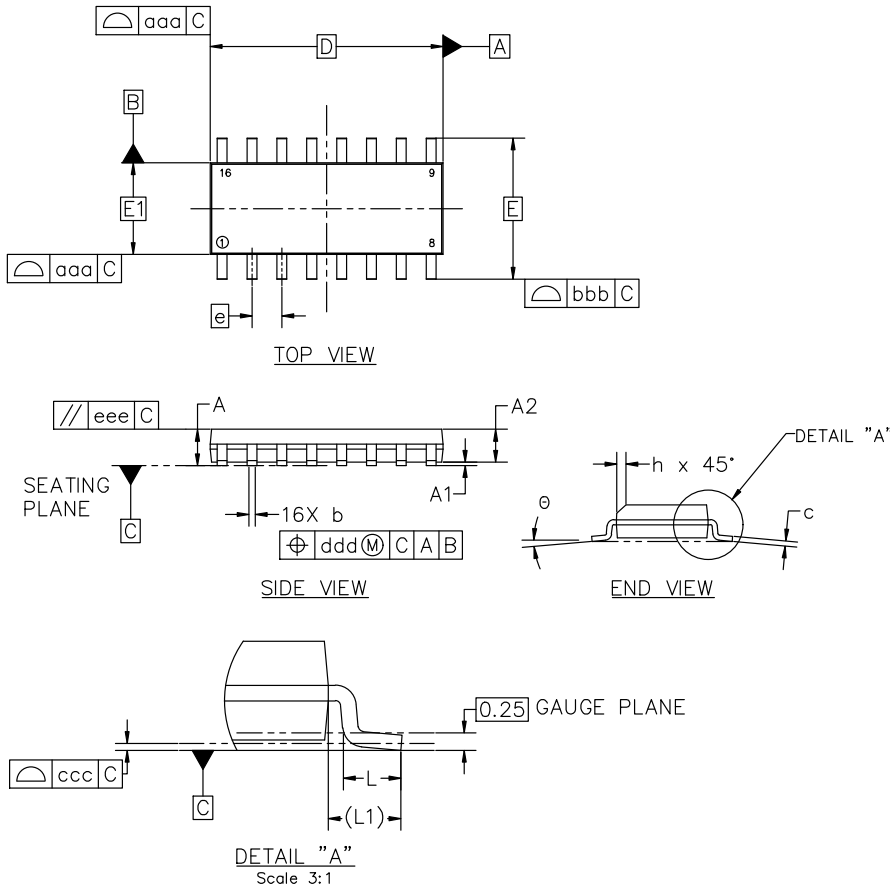


**SOIC-16 9.90x3.90x1.50 1.27P**  
**CASE 751B**  
**ISSUE L**

DATE 29 MAY 2024

**NOTES:**

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
2. DIMENSION IN MILLIMETERS. ANGLE IN DEGREES.
3. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15mm PER SIDE.
5. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127mm TOTAL IN EXCESS OF THE b DIMENSION AT MAXIMUM MATERIAL CONDITION.



MILLIMETERS			
DIM	MIN	NOM	MAX
A	1.35	1.55	1.75
A1	0.00	0.05	0.10
A2	1.35	1.50	1.65
b	0.35	0.42	0.49
c	0.19	0.22	0.25
D	9.90 BSC		
E	6.00 BSC		
E1	3.90 BSC		
e	1.27 BSC		
h	0.25	---	0.50
L	0.40	0.83	1.25
L1	1.05 REF		
θ	0°	---	7°
TOLERANCE OF FORM AND POSITION			
aaa	0.10		
bbb	0.20		
ccc	0.10		
ddd	0.25		
eee	0.10		



**RECOMMENDED MOUNTING FOOTPRINT**

\*FOR ADDITIONAL INFORMATION ON OUR PB-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE onsemi SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D

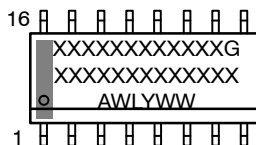
<b>DOCUMENT NUMBER:</b>	<b>98ASB42566B</b>	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
<b>DESCRIPTION:</b>	<b>SOIC-16 9.90X3.90X1.50 1.27P</b>	<b>PAGE 1 OF 2</b>

onsemi and ONSEMI are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

**SOIC-16 9.90x3.90x1.50 1.27P**  
**CASE 751B**  
**ISSUE L**

DATE 29 MAY 2024

**GENERIC MARKING DIAGRAM\***



XXXXX = Specific Device Code  
 A = Assembly Location  
 WL = Wafer Lot  
 Y = Year  
 WW = Work Week  
 G = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

<p><b>STYLE 1:</b></p> <p>PIN 1. COLLECTOR                  2. BASE                  3. EMITTER                  4. NO CONNECTION                  5. EMITTER                  6. BASE                  7. COLLECTOR                  8. COLLECTOR                  9. BASE                  10. EMITTER                  11. NO CONNECTION                  12. EMITTER                  13. BASE                  14. COLLECTOR                  15. EMITTER                  16. COLLECTOR</p>	<p><b>STYLE 2:</b></p> <p>PIN 1. CATHODE                  2. ANODE                  3. NO CONNECTION                  4. CATHODE                  5. CATHODE                  6. NO CONNECTION                  7. ANODE                  8. CATHODE                  9. CATHODE                  10. ANODE                  11. NO CONNECTION                  12. CATHODE                  13. CATHODE                  14. NO CONNECTION                  15. ANODE                  16. CATHODE</p>	<p><b>STYLE 3:</b></p> <p>PIN 1. COLLECTOR, DYE #1                  2. BASE, #1                  3. EMITTER, #1                  4. COLLECTOR, #1                  5. COLLECTOR, #2                  6. BASE, #2                  7. EMITTER, #2                  8. COLLECTOR, #2                  9. COLLECTOR, #3                  10. BASE, #3                  11. EMITTER, #3                  12. COLLECTOR, #3                  13. COLLECTOR, #4                  14. BASE, #4                  15. EMITTER, #4                  16. COLLECTOR, #4</p>	<p><b>STYLE 4:</b></p> <p>PIN 1. COLLECTOR, DYE #1                  2. COLLECTOR, #1                  3. COLLECTOR, #2                  4. COLLECTOR, #2                  5. COLLECTOR, #3                  6. COLLECTOR, #3                  7. COLLECTOR, #4                  8. COLLECTOR, #4                  9. BASE, #4                  10. EMITTER, #4                  11. BASE, #3                  12. EMITTER, #3                  13. BASE, #2                  14. EMITTER, #2                  15. BASE, #1                  16. EMITTER, #1</p>
<p><b>STYLE 5:</b></p> <p>PIN 1. DRAIN, DYE #1                  2. DRAIN, #1                  3. DRAIN, #2                  4. DRAIN, #2                  5. DRAIN, #3                  6. DRAIN, #3                  7. DRAIN, #4                  8. DRAIN, #4                  9. GATE, #4                  10. SOURCE, #4                  11. GATE, #3                  12. SOURCE, #3                  13. GATE, #2                  14. SOURCE, #2                  15. GATE, #1                  16. SOURCE, #1</p>	<p><b>STYLE 6:</b></p> <p>PIN 1. CATHODE                  2. CATHODE                  3. CATHODE                  4. CATHODE                  5. CATHODE                  6. CATHODE                  7. CATHODE                  8. CATHODE                  9. ANODE                  10. ANODE                  11. ANODE                  12. ANODE                  13. ANODE                  14. ANODE                  15. ANODE                  16. ANODE</p>	<p><b>STYLE 7:</b></p> <p>PIN 1. SOURCE N-CH                  2. COMMON DRAIN (OUTPUT)                  3. COMMON DRAIN (OUTPUT)                  4. GATE P-CH                  5. COMMON DRAIN (OUTPUT)                  6. COMMON DRAIN (OUTPUT)                  7. COMMON DRAIN (OUTPUT)                  8. SOURCE P-CH                  9. SOURCE P-CH                  10. COMMON DRAIN (OUTPUT)                  11. COMMON DRAIN (OUTPUT)                  12. COMMON DRAIN (OUTPUT)                  13. GATE N-CH                  14. COMMON DRAIN (OUTPUT)                  15. COMMON DRAIN (OUTPUT)                  16. SOURCE N-CH</p>	

<b>DOCUMENT NUMBER:</b>	<b>98ASB42566B</b>	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
<b>DESCRIPTION:</b>	<b>SOIC-16 9.90X3.90X1.50 1.27P</b>	<b>PAGE 2 OF 2</b>

onsemi and onsemi are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

# MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS



**TSSOP-16 WB**  
CASE 948F  
ISSUE B

DATE 19 OCT 2006

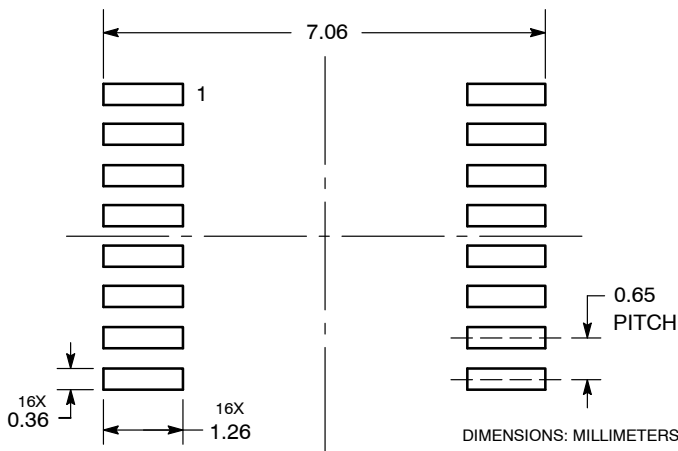


**NOTES:**

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: MILLIMETER.
- DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
- DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
- DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
- TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
- DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.90	5.10	0.193	0.200
B	4.30	4.50	0.169	0.177
C	---	1.20	---	0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
H	0.18	0.28	0.007	0.011
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
M	0°	8°	0°	8°

**RECOMMENDED  
SOLDERING FOOTPRINT\***



**GENERIC  
MARKING DIAGRAM\***



- XXXX = Specific Device Code
- A = Assembly Location
- L = Wafer Lot
- Y = Year
- W = Work Week
- G or ■ = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

\*For additional information on our Pb-Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

<b>DOCUMENT NUMBER:</b>	<b>98ASH70247A</b>	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
<b>DESCRIPTION:</b>	<b>TSSOP-16</b>	<b>PAGE 1 OF 1</b>

onsemi and onsemi are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

**onsemi**, **Onsemi**, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "**onsemi**" or its affiliates and/or subsidiaries in the United States and/or other countries. **onsemi** owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of **onsemi**'s product/patent coverage may be accessed at [www.onsemi.com/site/pdf/Patent-Marking.pdf](http://www.onsemi.com/site/pdf/Patent-Marking.pdf). **onsemi** reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and **onsemi** makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

## ADDITIONAL INFORMATION

### TECHNICAL PUBLICATIONS:

Technical Library: [www.onsemi.com/design/resources/technical-documentation](http://www.onsemi.com/design/resources/technical-documentation)  
onsemi Website: [www.onsemi.com](http://www.onsemi.com)

### ONLINE SUPPORT: [www.onsemi.com/support](http://www.onsemi.com/support)

For additional information, please contact your local Sales Representative at [www.onsemi.com/support/sales](http://www.onsemi.com/support/sales)